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Vishay/Siliconix DG9636EN-T1-E4

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Datasheet of DG9636EN-T1-E4 - IC SWITCH DUAL SPST 10QFN

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Dual SPDT Analog Switch

DESCRIPTION

The DG9636 is a CMOS, dual SPDT analog switch designed to operate from 2.7 V to 12 V, single supply. All control logic inputs have a guaranteed 1.65 V logic HIGH threshold when operation from a 12 V power supply. This makes the DG9636 ideally suited to interface directly with low voltage micro-processor control signals.

Processed with high density CMOS technology, the DG9636 has a 83 Ω channel ON resistance while providing ultra low parasitic capacitance of 2 pF for CS_(off) and 7 pF for CD_(on). Other performance features are: 720 MHz -3 dB bandwidth, -67 dB Cross Talk and -58 dB Off isolation at 10 MHz frequency.

Key applications for the DG9636 are logic level translation, pulse generator, and high speed or low noise signal switching in precision instrumentations and portable device designs.

The DG9636 is available in space saving 1.4 mm x 1.8 mm miniQFN10 package.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device termination. The miniQFN-10 package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix to the ordering part number. The nickel-palladium-gold device terminations meet all JEDEC® standards for reflow and MSL rating.

FEATURES

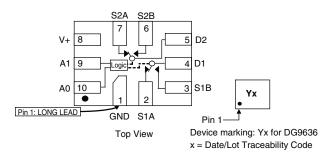
- Leakage current < 0.5 nA max. at 85 °C
- Low switch capacitance (C_{soff}, 2 pF typ.)
- R_{DS(on)} -83 Ω max.
- Low voltage, 1.65 V CMOS/TTL compatible
- 720 MHz, -3 dB bandwidth
- Fully specified with single supply operation at 12 V
- Excellent isolation and crosstalk performance (typ. > -60 dB at 10 MHz)
- Fully specified from -40 °C to 85 °C and -40 °C to +125 °C
- Latch-up current 300 mA per JESD78
- Lead (Pb)-free low profile miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm)
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · High-end data acquisition
- · Medical instruments
- Precision instruments
- High speed communications applications
- Automated test equipment
- · Sample and hold applications

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG9636 miniQFN - 10L



TRUTH TABLE		
Selec	ted Input	On Switches
A1	A0	DG9636
Х	0	D1 to S1A
Х	1	D1 to S1B
0	X	D2 to S2A
1	X	D2 to S2B

S14-0483-Rev. C, 10-Mar-14 **1** Document Number: 65159

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ORDERING INFORMA	TION	
Temp. Range	Package	Part Number
-40 °C to 125 °C	10 pin miniQFN	DG9636EN-T1-E4
-40 °C to 85 °C	10 pin miniQFN	DG9636DN-T1-E4

Note

• -40 °C to 85 °C datasheet limits apply.

ABSOLUTE MAXIMUM RATI	NGS (T _A = 25 °C, unless ot	nerwise noted)	
Parameter		Limit	Unit
V+ to GND		14	V
Digital Inputs ^a , V _S , V _D		(V+) +0.3 or 30 mA, whichever occurs first	V
Continuous Current (Any Terminal)		30	A
Peak Current, S or D (Pulsed 1 ms, 10 %	5 Duty Cycle)	100	mA
Storage Temperature		-65 to 150	°C
Power Dissipation (Package) b	10 pin miniQFN ^{c, d}	208	mW
Thermal Resistance (Package) b	10 pin miniQFN	357	°C/W

Notes

- a. Signals on SX, DX, or AX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 2.6 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-10 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

SPECIFICATIONS									
_		Test Conditions		_	-40 °C t	o 125 °C	-40 °C	to 85 °C	
Parameter	Symbol	Unless Otherwise Specified $V+ = 12 \text{ V}, V_{A0, A1} = 1.65 \text{ V}, 0.5 \text{ V}^{\text{a}}$	Temp. ^b	Typ. ^c	Min. d	Max. d	Min. d	Max. d	Unit
Analog Switch									
Analog Signal Range e	V _{ANALOG}		Full	ı	-	12	ı	12	V
On-Resistance	P	$I_S = 1 \text{ mA, } V_D = +11.3 \text{ V}$	Room	83	-	110	ı	110	
On-nesistance	R _{DS(on)}	IS - 1 IIIA, VD - +11.3 V	Full	-	-	140	-	125	
On-Resistance Match	ΔR_{on}	$I_S = 1 \text{ mA, } V_D = +11.3 \text{ V}$	Room	2	-	4	-	4	Ω
On-nesistance materi	Δn _{on}	$i_S = i \text{ TIA}, v_D = +ii.3 \text{ V}$	Full	-	-	9	-	6	32
On-Resistance Flatness	В	I _S = 1 mA, V _D = 0.7 V, 6.5 V, 11.3 V	Room	33	-	45	-	45	
On-nesistance riathess	R _{FLATNESS}	15 - 1 1111 (, V _D = 0.7 V, 0.0 V, 11.0 V	Full	-	-	55	-	50	
			Room	± 0.01	-1	1	-1	1	
Switch Off	I _{S(off)}	V+ = 12 V, V _D = 1 V/11 V, V _S = 11 V/1 V	Full	-	-18	18	-2	2	
Leakage Current			Room	± 0.01	-1	1	-1	1	nA
	I _{D(off)}		Full	-	-18	18	-2	2	IIA
Channel On		V+ = 12 V,	Room	± 0.01	-1	1	-1	1	
Leakage Current	I _{D(on)}	V _D = V _S 11 V/1 V	Full	-	-18	18	-2	2	
Digital Control									
Input Current, V _{IN} Low	I _{IL}	V _{AX} = 0.5 V	Full	0.005	-0.1	0.1	-0.1	0.1	
Input Current, V _{IN} High	I _{IH}	V _{AX} = 1.65 V	Full	0.005	-0.1	0.1	-0.1	0.1	μA
Input Capacitance e	C _{IN}	f = 1 MHz	Room	3	-	-	-	-	рF

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SPECIFICATIONS									
		Test Conditions			-40 °C t	o 125 °C	-40 °C	to 85 °C	
Parameter	Symbol	Unless Otherwise Specified V+ = 12 V, V _{A0, A1} = 1.65 V, 0.5 V ^a	Temp. ^b	Typ. ^c	Min. ^d	Max. d	Min. ^d	Max. d	Unit
Dynamic Characteristics	5								
Turn-On Time	t _{on}		Room	30	-	70	-	70	
Turn-On Time	Lon		Full	-	-	90	-	80	
Turn-Off Time	+	$R_L = 300 \Omega, C_L = 35 pF$	Room	15	-	55	-	55	20
Turn-On Time	t _{off}	see figure 1, 2	Full	-	-	75	-	65	ns
Durali Dafana Malia			Room	15	5	-	5	-	
Break-Before-Make	t _{BBM}		Full	-	2	-	2	-	
Charge Injection e	Q _{INJ}	$V_{g} = 0 \text{ V}, R_{g} = 0 \Omega, C_{L} = 1 \text{ nF}$	Room	23.5	-	-	-	-	рС
Off Isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 10 MHz$	Room	-58	-	-	-	-	dB
Bandwidth ^e	BW	$R_L = 50 \Omega$	Room	720	-	-	-	-	MHz
Channel-to-Channel Crosstalk ^e	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 10 MHz$	Room	-67	_	-	-	-	dB
Dynamic Characteristics	5								
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	2	-	_	-	-	
Channel On Capacitance ^e	C _{D(on)}	I = I WINZ	Room	7.7	-	-	-	-	pF
Total Harmonic Distortion ^e	THD	Signal = 1 V_{RMS} , 20 Hz to 20 kHz, $R_L = 600 \Omega$	Room	0.01	-	-	-	-	%
Power Supplies									
Devices Comply Com	1.		Room	0.001	-	0.5	-	0.5	
Power Supply Current	I+	V 0V 2*V	Full	-	-	1	-	1	
Cround Comment		$V_{IN} = 0 V$, or V+	Room	-0.001	-0.5	-	-0.5	-	μA
Ground Current	I _{GND}		Full	-	-1	-	-1	-	

SPECIFICATIONS									
_		Test Conditions			-40 °C t	o 125 °C	-40 °C t	to 85 °C	
Parameter	Symbol	Unless Otherwise Specified $V+=5 V$, $V_{A0, A1}=1.4 V$, $0.5 V$ a	Temp. ^b	Typ. ^c	Min. d	Max. d	Min. d	Max. d	Unit
Analog Switch									
Analog Signal Range e	V _{ANALOG}		Full	-	-	5	-	5	V
On-Resistance	D		Room	120	-	170	-	170	
On-nesistance	R _{DS(on)}	$I_S = 1 \text{ mA}, V_D = +3.5 \text{ V}$	Full	-	-	250	-	200	Ω
On-Resistance Match	ΔR_{on}	$i_S = 1$ ma, $v_D = +3.5$ v	Room	3	-	5	-	5	5.2
On-nesistance Match	Δη _{on}		Full	-	-	12	-	10	
	I _{S(off)}		Room	± 0.01	-1	1	-1	1	
Switch Off		V+ = 5.5 V, $V_D = 1 \text{ V}/4.5 \text{ V}, V_S = 4.5 \text{ V}/1 \text{ V}$	Full	-	-18	18	-2	2	<u>_</u>
Leakage Current			Room	± 0.01	-1	1	-1	1	nA
	I _{D(off)}		Full	-	-18	18	-2	2	IIA
Channel On		$V+ = 5.5 \text{ V}, V_S = V_D = 1 \text{ V}/4.5 \text{ V}$	Room	± 0.01	-1	1	-1	1	
Leakage Current	I _{D(on)}	$V + = 5.5 \text{ V}, V_S = V_D = 1 \text{ V}/4.5 \text{ V}$	Full	-	-18	18	-2	2	
Digital Control									
Input Current, V _{IN} Low	ΙL	V _{AX} = 0.5 V	Full	0.005	-0.1	0.1	-0.1	0.1	μA
Input Current, V _{IN} High	I _H	V _{AX} = 1.4 V	Full	0.005	-0.1	0.1	-0.1	0.1	μΑ
Input Capacitance	C _{IN}	f = 1 MHz	Room	3	-	-	-	-	pF



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SPECIFICATIONS									
		Test Conditions			-40 °C to	o 125 °C	-40 °C 1	to 85 °C	
Parameter	Symbol	Unless Otherwise Specified $V+=5 V$, $V_{A0, A1}=1.4 V$, $0.5 V$ a	Temp. ^b	Typ. ^c	Min. d	Max. d	Min. ^d	Max. d	Unit
Dynamic Characteristics									
Turn-On Time	+		Room	55	-	-	-	-	
rum-on nine	t _{on}		Full	-	-	-	-	-	
Turn-Off Time		$R_L = 300 \Omega, C_L = 35 pF$	Room	30	-	-	-	-	
rum-On time	t _{off}	see figure 1, 2	Full	-	-	-	-	-	ns
D D (M T			Room	36	-	-	-	-	
Break-Before-Make-Time	t _{BMM}		Full	-	-	-	-	-	
Charge Injection e	Q _{INJ}	$C_L = 1 \text{ nF}, R_{GEN} = 0 \Omega, V_{GEN} = 0 V$	Full	10	-	-	-	-	рС
Off-Isolation ^e	OIRR	£ 10 MIL- D 50 0 0 5 mE	Room	-58	-	-	-	-	dB
Crosstalk e	X _{TALK}	f = 10 MHz, R_L = 50 Ω, C_L = 5 pF	Room	-68	-	-	-	-	ав
Bandwidth ^e	BW	$R_L = 50 \Omega$	Room	610	-	-	-	-	MHz
Total Harmonic Distortion ^e	THD	Signal = 1 V_{RMS} , 20 Hz to 20 kHz, $R_L = 600 \Omega$	Room	2.2	-	-	-	-	%
Source Off Capacitance e	C _{S(off)}			2.1	-	-	-	-	
Channel On Capacitance ^e	C _{D(on)}	f = 1 MHz	Room	8.1	-	-	-	-	pF
Power Supplies									
Power Supply Current	I+		Room	0.001	-	0.5	-	0.5	
rower Supply Current	I+	V 0V 2*V	Full	-	-	1	-	1	
Cupum d Cummant		$V_{IN} = 0 V$, or V+	Room	-0.001	-0.5	-	-0.5	-	μA
Ground Current	I _{GND}		Full	-	-1	-	-1	-	

SPECIFICATIONS									
_		Test Conditions			-40 °C t	o 125 °C	-40 °C	to 85 °C	J
Parameter	Symbol	Unless Otherwise Specified $V+=3 V$, $V_{A0, A1}=1.4 V$, $0.5 V$ a	Temp.b	Typ. ^c	Min. ^d	Max. d	Min. ^d	Max. d	Unit
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full	-	-	3	-	3	V
On-Resistance	В		Room	200	-	245	-	245	
On-nesistance	R _{DS(on)}	Is = 1 mA. V _D = +1.5 V	Full	-	-	325	-	290	Ω
On-Resistance Match	A.D.	IS = I IIIA, VD = +1.5 V	Room	5	-	6	-	6	1 22
On-nesistance Match	ΔR_{on}		Full	-	-	13	-	11	
			Room	± 0.01	-1	1	-1	1	
Switch Off Leakage Current	I _{S(off)}	V+ = 3.3 V, V- = 0 V	Full	-	-18	18	-2	2	
(for 16 pin miniQFN)		$V_D = 1 \text{ V/3 V}, V_S = 3 \text{ V/1 V}$	Room	± 0.01	-1	1	-1	1	
	I _{D(off)}		Full	-	-18	18	-2	2	nA
Channel On		V+ = 3.3 V. V- = 0 V.	Room	± 0.01	-1	1	-1	1	
Leakage Current (for 16 pin miniQFN)	I _{D(on)}	$V_S = V_D = 1 \text{ V/3 V}$	Full	-	-18	18	-2	2	
Digital Control									
Input Current, V _{IN} Low	Ι <u></u>	$V_{AX} = 0.5 \text{ V}$	Full	0.005	-0.1	0.1	-0.1	0.1	
Input Current, V _{IN} High	I _H	V _{AX} = 1.4 V	Full	0.005	-0.1	0.1	-0.1	0.1	μA
Input Capacitance	C _{IN}	f = 1 MHz	Room	3.1	-	-	-	-	pF

S14-0483-Rev. C, 10-Mar-14

Document Number: 65159

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SPECIFICATIONS									
		Test Conditions			-40 °C t	o 125 °C	-40 °C	to 85 °C	
Parameter	Symbol	Unless Otherwise Specified $V+=3~V,~V_{A0,~A1}=1.4~V,~0.5~V~a$	Temp.b	Typ. ^c	Min. ^d	Max. d	Min. d	Max. d	Unit
Dynamic Characteristics									
Enable Turn-On Time			Room	96	-	-	-	-	
Enable fulli-On fillie	t _{on}		Full	-	-	-	-	-	
Enable Turn-Off Time	+	$R_L = 300 \Omega, C_L = 35 pF$	Room	60	-	-	-	-	ns
Enable fulli-Oil fillie	t _{off}	see figure 1, 2	Full	-	-	-	-	-	
Break-Before-Make-Time			Room	77	-	-	-	-	
break-belore-wake-Time	t _{BMM}		Full	-	-	-	-	-	
Charge Injection e	Q _{INJ}	$C_L = 1 \text{ nF}, R_{GEN} = 0 \Omega, V_{GEN} = 0 V$	Full	6.6	-	-	-	-	рС
Off-Isolation e	OIRR	f = 10 MHz	Room	-57	-	-	-	-	dB
Crosstalk ^e	X _{TALK}	f = 10 MHz, R_L = 50 Ω, C_L = 5 pF	Room	-69	-	-	-	-	uБ
Bandwidth ^e	BW	$R_L = 50 \Omega$	Room	525	-	-	-	-	MHz
Total Harmonic Distortion ^e	THD	Signal = 1 V_{RMS} , 20 Hz to 20 kHz, $R_L = 600 \Omega$	Room	2.2	-	-	-	-	%
Source Off Capacitance e	C _{S(off)}			2.1	-	-	-	-	
Channel On Capacitance ^e	C _{D(on)}	f = 1 MHz	Room	8.3	-	-	-	-	pF
Power Supplies									
Power Supply Current	I+		Room	0.001	-	0.5	-	0.5	
Fower Supply Current	I+	V = 0 V or V	Full	-	-	1	-	1	
Ground Current	I	$V_{IN} = 0 \text{ V, or V+}$	Room	-0.001	-0.5	-	-0.5	-	μA
Ground Current	I _{GND}		Full	-	-1	-	-1	-	

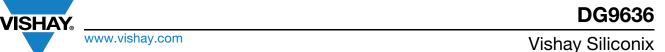
Notes

- a. V_{IN} = input voltage to perform proper function.
- b. Room = 25 $^{\circ}$ C, Full = as determined by the operating temperature.
- c. Typical value are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- e. Guaranteed by design, not subject to production test.

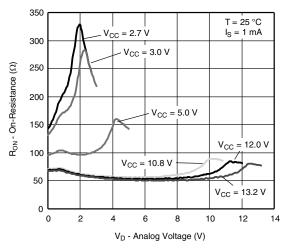
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Datasheet of DG9636EN-T1-E4 - IC SWITCH DUAL SPST 10QFN

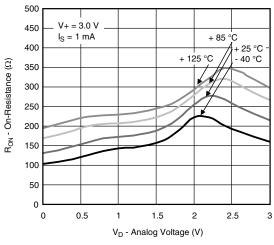
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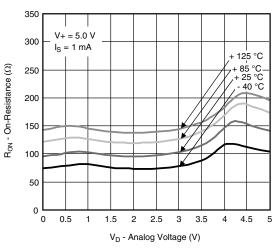
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



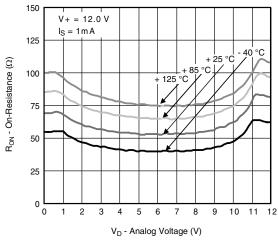
On-Resistance vs. Single Supply Voltage



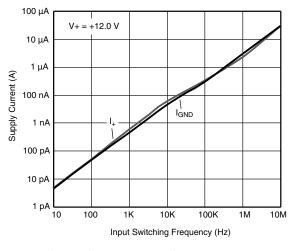
On-Resistance vs. Analog Voltage and Temperature



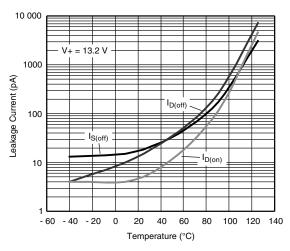
On-Resistance vs. Analog Voltage and Temperature



On-Resistance vs. Analog Voltage and Temperature



Supply Current vs. Input Switching Frequency



Leakage Current vs. Temperature

S14-0483-Rev. C, 10-Mar-14 Document Number: 65159 6

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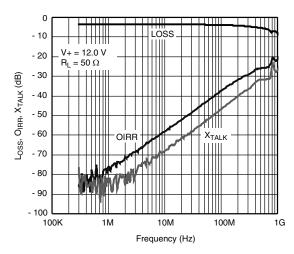


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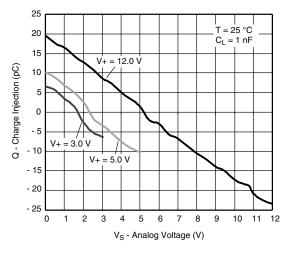
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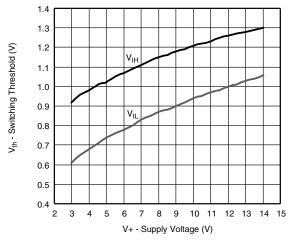
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



Charge Injection vs. Analog voltage



Switching Threshold vs. Supply Voltage

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TEST CIRCUITS

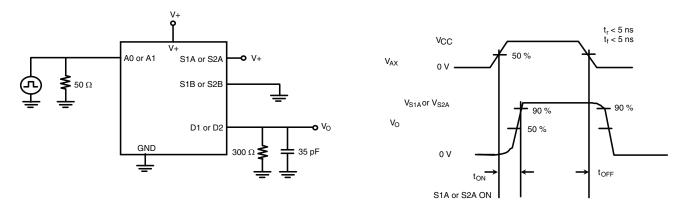


Figure 1. Enable Switching Time

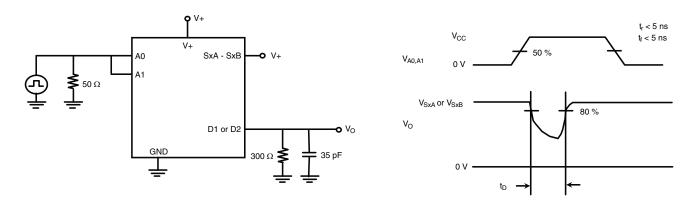


Figure 2. Break-Before-Make

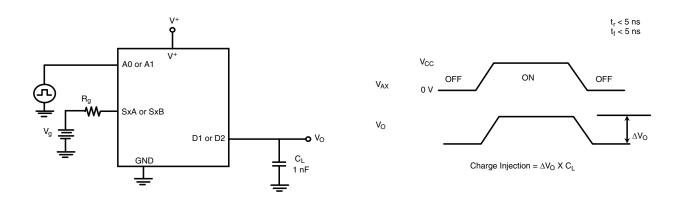


Figure 3. Charge Injection

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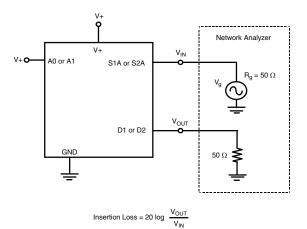


Figure 4. Insertion Loss

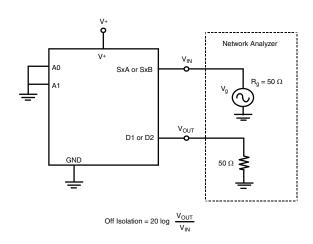


Figure 5. Off-Isolation

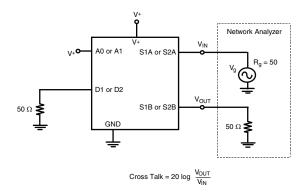


Figure 6. Crosstalk

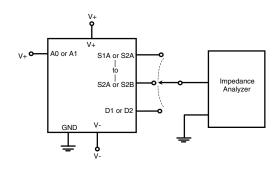


Figure 7. Source/Drain Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65159.

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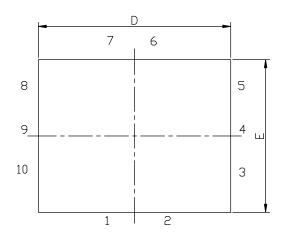


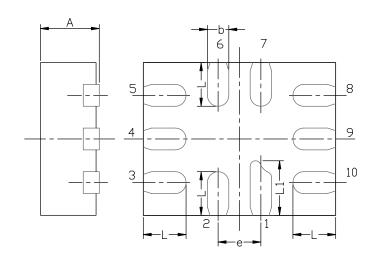
Package Information

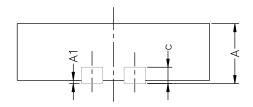
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MINI QFN-10L CASE OUTLINE







DIM		MILLIMETERS			INCHES	
DIM	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.
Α	0.45	0.55	0.60	0.0177	0.0217	0.0236
A1	0.00	-	0.05	0.000	-	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
С		0.150 or 0.127 REF ⁽	1)	(0.006 or 0.005 REF (1)
D	1.70	1.80	1.90	0.067	0.071	0.075
E	1.30	1.40	1.50	0.051	0.055	0.059
е		0.40 BSC			0.016 BSC	
L	0.35	0.40	0.45	0.014	0.016	0.018
L1	0.45	0.50	0.55	0.0177	0.0197	0.0217

Note

ECN T16-0163-Rev. B, 16-May-16 DWG: 5957

Revision: 16-May-16 1 Document Number: 74496

⁽¹⁾ The dimension depends on the leadframe that assembly house used.

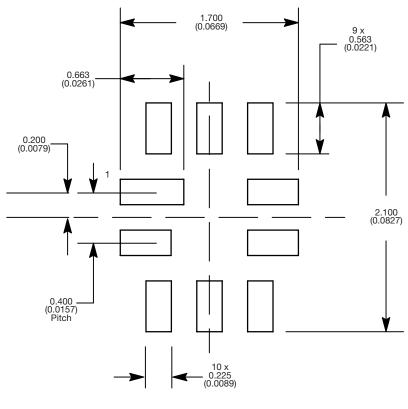




PAD Pattern

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RECOMMENDED MINIMUM PADS FOR MINI QFN 10L



Mounting Footprint Dimensions in mm (inch)

Document Number: 66554 www.vishay.com Revision: 05-Mar-10



Datasheet of DG9636EN-T1-E4 - IC SWITCH DUAL SPST 10QFN

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